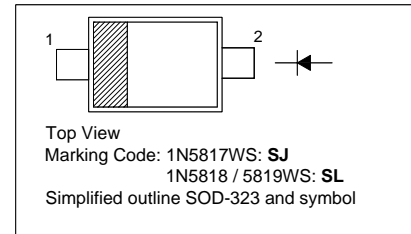


1 A Surface Mount Schottky Barrier Diode

1N5817WS~1N5819WS

PINNING

PIN	DESCRIPTION
1	Cathode
2	Anode



Absolute Maximum Ratings ($T_a = 25\text{ }^\circ\text{C}$)

Parameter	Symbol	Value	Unit
Reverse Voltage	V_R	1N5817WS	20
		1N5818WS	30
		1N5819WS	40
Average Forward Rectified Current	$I_{F(AV)}$	1	A
Non-Repetitive Peak Forward Surge Current ($t = 8.3\text{ ms}$)	I_{FSM}	9	A
Power Dissipation	P_{tot}	450	mW
Operating Temperature Range	T_j	- 55 to + 125	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	- 55 to + 125	$^\circ\text{C}$

Characteristics at $T_a = 25\text{ }^\circ\text{C}$

Parameter	Symbol	Min.	Max.	Unit
Reverse Breakdown Voltage at $I_R = 1\text{ mA}$	$V_{(BR)R}$	1N5817WS	20	-
		1N5818WS	30	-
		1N5819WS	40	-
Forward Voltage at $I_F = 1\text{ A}$ at $I_F = 3\text{ A}$	V_F	1N5817WS	-	0.45
		1N5818WS	-	0.55
		1N5819WS	-	0.6
		1N5817WS	-	0.75
		1N5818WS	-	0.875
		1N5819WS	-	0.9
Reverse Voltage Leakage Current at $V_R = 20\text{ V}$ at $V_R = 30\text{ V}$ at $V_R = 40\text{ V}$	I_R	1N5817WS	-	1
		1N5818WS	-	1
		1N5819WS	-	1
Total Capacitance at $V_R = 4\text{ V}$, $f = 1\text{ MHz}$	C_{tot}	-	120	pF

1N5817WS~1N5819WS

Fig. 1 - Forward Current Derating Curve

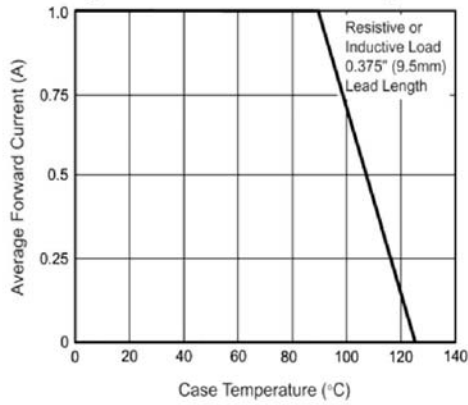


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current

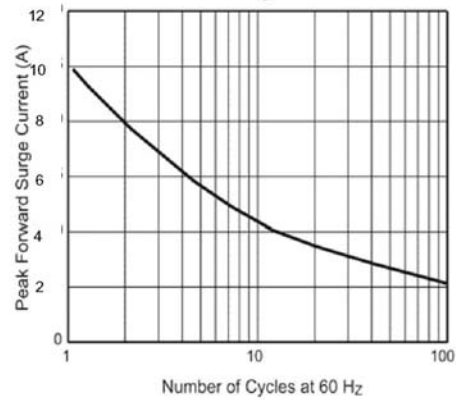


Fig. 3 - Typical Instantaneous Forward Characteristics

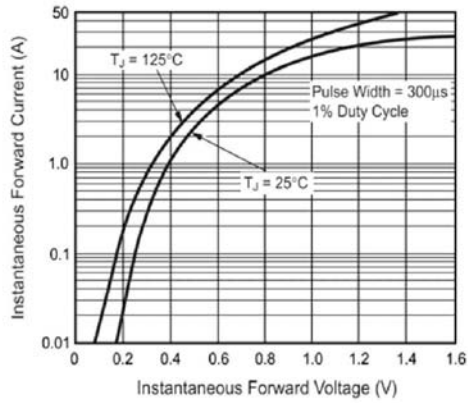


Fig. 4 - Typical Reverse Characteristics

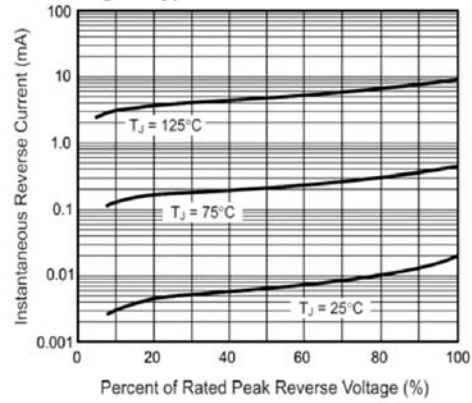


Fig. 5 - Typical Junction Capacitance

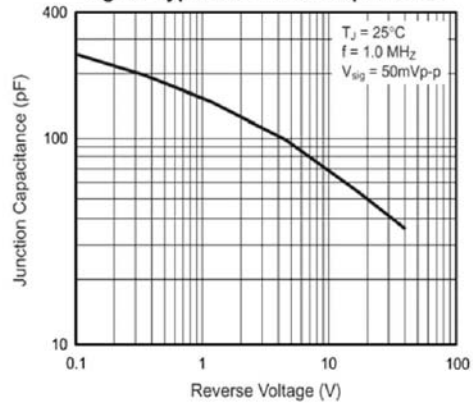
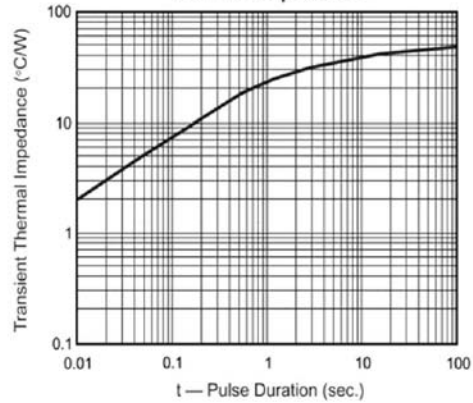


Fig. 6 - Typical Transient Thermal Impedance



PACKAGE OUTLINE 1N5817WS~1N5819WS

Plastic surface mounted package; 2 leads

SOD-323

